

November 1999 Revised December 1999

# USB1T11A Universal Serial Bus Transceiver

## **General Description**

The USB1T11A is a one chip generic USB transceiver. It is designed to allow 5.0V or 3.3V programmable and standard logic to interface with the physical layer of the Universal Serial Bus. It is capable of transmitting and receiving serial data at both full speed (12Mbit/s) and low speed (1.5Mbit/s) data rates.

The input and output signals of the USB1T11A conform with the "Serial Interface Engine". Implementation of the Serial Interface Engine along with the USB1T11A allows the designer to make USB compatible devices with off-the-shelf logic and easily modify and update the application.

#### **Features**

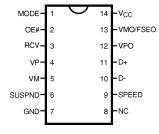
- Complies with Universal Serial Bus specification 1.1
- Utilizes digital inputs and outputs to transmit and receive USB cable data
- Supports 12Mbit/s "Full Speed" and 1.5Mbit/s "Low Speed" serial data transmission
- Compatible with the VHDL "Serial Interface Engine" from USB Implementers' Forum
- Supports single-ended data interface
- Single 3.3V supply
- ESD Performance : Human Body Model > 4000 V

## **Ordering Code:**

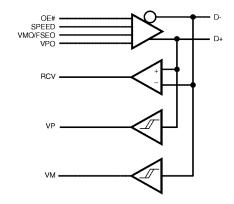
Order Number	Package Number	Package Description
USB1T11AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
USB1T11AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

# **Connection Diagram**



# **Logic Diagram**



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DS500234

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# **Pin Descriptions**

Pin Name	I/O			Description					
RCV	0	Receive data. CMOS level output for USB differential input							
OE#	I		Output Enable. Active LOW, enables the transceiver to transmit data on the bus. When not active the transceiver is in receive mode.						
MODE	I		lode. When left unconnected, a weak pull-up transistor pulls it to V <sub>CC</sub> and in this GND, the MO/FSEO pin takes the function of FSEO (Force SEO).						
		Inputs to differential d	river. (Outputs fror	n SIE).					
		MODE	VPO	VMO/FSEO	RESULT				
		0	0	0	Logic "0"				
			0	1	SE0#				
., ., ./=			1	0	Logic "1"				
V <sub>PO</sub> , V <sub>MO</sub> /F <sub>SEO</sub>	ı		1	1	SEO#				
		1	0	0	SE0#				
			0	1	Logic "0"				
			1	0	Logic "1"				
			1	1	Illegal code				
		Gated version of D- and D+. Outputs are logic "0" and logic "1". Used to detect si zero (SE0#), error conditions, and interconnect speed. (Input to SIE).							
		VP	VM	RESULT					
$V_{P}, V_{M}$	0	0	0	SE0#					
1 . 141		0	1	Low Speed					
		1	0	Full Speed					
		1	1	Error					
D+, D-	AI/O	Data+, Data Differer	ntial data bus confe	orming to the Universal Se	rial Bus standard.				
SUSPND	I		Suspend. Enables a low power state while the USB bus is inactive. While the suspend pin is active it will drive the RCV pin to a logic "0" state. Both D+ and D- are 3-STATE.						
SPEED	I	Edge rate control. Logic "1" operates at edge rates for "full speed". Logic "0" operates edge rates for "low speed".							
V <sub>CC</sub>		3.0V to 3.6V power su	upply						
GND		Ground reference							

# **Functional Truth Table**

		Input			I/	0		Outputs		
Mode	VPO	VMO/FSEO	OE	SUSPND	D+	D-	RCV	V <sub>P</sub>	V <sub>M</sub>	Result
0	0	0	0	0	0	1	0	0	1	Logic 0
0	0	1	0	0	0	0	U	0	0	SEO#
0	1	0	0	0	1	0	1	1	0	Logic 1
0	1	1	0	0	0	0	U	0	0	SEO#
1	0	0	0	0	0	0	U	0	0	SEO#
1	0	1	0	0	0	1	0	0	1	Logic 0
1	1	0	0	0	1	0	1	1	0	Logic 1
1	1	1	0	0	1	1	U	U	U	Illegal Code
X	Х	Х	1	0	Z	Z	U	U	U	D+/D- Hi-Z
X	Х	Х	1	1	Z	Z	U	U	U	D+/D- Hi-Z

X = Don't Care Z = 3-STATE U = Undefined State

# Absolute Maximum Ratings(Note 1) Re

DC Input Diode Current (I<sub>IK</sub>)

 $V_{\rm I}$  < 0 —50 mA Input Voltage (V<sub>I</sub>)

(Note 2) -0.5V to +5.5V

Input Voltage (V<sub>I/O</sub>)  $-0.5V \text{ to V}_{CC} + 0.5V$ 

Output Diode Current (I<sub>OK</sub>)

 $V_O > V_{CC}$  or  $V_O < 0$  ±50 mA

Output Voltage (V<sub>O</sub>)

(Note 2)  $-0.5V \text{ to V}_{CC} + 0.5V$ 

Output Source or Sink Current (I<sub>O</sub>)

VP.VM, RCV pins

 $V_O = 0$  to  $V_{CC}$  ±15 mA

Output Source or Sink Current (I<sub>O</sub>)

D+/D- pins

 $V_{O}$  = 0 to  $V_{CC}$  ±50 mA  $V_{CC}$  or GND Current ( $I_{CC}$ ,  $I_{GND}$ ) ±100 mA

Storage Temperature (T $_{STO}$ )  $-60^{\circ}$ C to + 150 $^{\circ}$ C

# Recommended Operating Conditions

Supply Voltage V<sub>CC</sub> 3.0V to 3.6V

 $\label{eq:local_$ 

Operating Ambient Temperature

in free air ( $T_{amb}$ )  $-40^{\circ}$ C to  $+85^{\circ}$ C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristic tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

#### DC Electrical Characteristics (Digital Pins)

Over recommended range of supply voltage and operating free air temperature (unless otherwise noted).  $V_{CC} = 3.0 V$  to 3.6V

				Unit		
Symbol	Parameter	Test Conditions	Temp			
			Min	Тур	Max	Ī
	INPUT LEVELS:				•	
V <sub>IL</sub>	LOW Level Input Voltage				0.8	V
V <sub>IH</sub>	HIGH Level Input Voltage		2.0			V
	OUTPUT LEVELS:				•	
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 4 mA			0.4	V
		$I_{OL} = 20 \mu A$			0.1	1 °
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = 4 mA	2.4			V
		$I_{OH} = 20 \mu A$	V <sub>CC</sub> - 0.1			1 v
	LEAKAGE CURRENT:				•	
IL	Input Leakage Current	V <sub>CC</sub> = 3.0 to 3.6			±5	μΑ
I <sub>CCFS</sub>	Supply Current (Full Speed)	V <sub>CC</sub> = 3.0 to 3.6			5	mA
I <sub>CCLS</sub>	Supply Current (Low Speed)	V <sub>CC</sub> = 3.0 to 3.6			5	mA
I <sub>CCQ</sub>	Quiescent Current	V <sub>CC</sub> = 3.0 to 3.6			5	mA
		$V_{IN} = V_{CC}$ or GND			3	IIIA
I <sub>CCS</sub>	Supply Current in Suspend	$V_{CC} = 3.0$ to 3.6; Mode = $V_{CC}$			10	μА

# DC Electrical Characteristics (D+/D- Pins)

Over recommended range of supply voltage and operating free air temperature (unless otherwise noted).  $V_{CC} = 3.0 \text{V}$  to 3.6 V

		Test Conditions		Units		
Symbol	Parameter		Tem			
			Min	Тур	Max	1
	INPUT LEVELS:			•	•	•
$V_{DI}$	Differential Input Sensitivity	(D+) - (D-)	0.2			V
V <sub>CM</sub>	Differential Common Mode Range	Includes V <sub>DI</sub> Range	0.8		2.5	V
V <sub>SE</sub>	Single Ended Receiver Threshold		0.8		2.0	V
	OUTPUT LEVELS:		•			
V <sub>OL</sub>	Static Output LOW Voltage	$R_L$ of 1.5 k $\Omega$ to 3.6V			0.3	V
V <sub>OH</sub>	Static Output HIGH Voltage	$R_L$ of 15 k $\Omega$ to GND	2.8		3.6	V
V <sub>CR</sub>	Differential Crossover		1.3		2.0	V
	LEAKAGE CURRENT:				ı	
l <sub>oz</sub>	High Z State Data Line Leakage Current	0V < V <sub>IN</sub> < 3.3V			±5	μА
	CAPACITANCE:		•			
C <sub>IN</sub> (Note 4)	Transceiver Capacitance	Pin to GND			10	pF
	Capacitance Match				10	%
	OUTPUT RESISTANCE:	1				1
Z <sub>DRV</sub> (Note 3)	Driver Output Resistance	Steady State Drive	4		20	Ω
	Resistance Match				10	%

Note 3: Excludes external resistor. In order to comply with USB Specification 1.1, external series resistors of 24Ω ± 1% each on D+ and D− are recommended. This specification is guaranteed by design and statistical process distribution.

Note 4: This specification is guaranteed by design and statistical process distribution.

## AC Electrical Characteristics (D+/D- Pins, Full Speed)

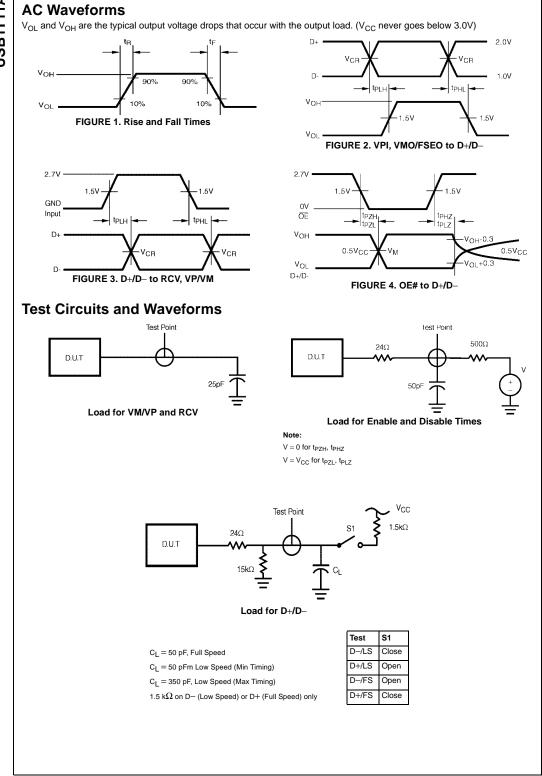
Over recommended range of supply voltage and operating free air temperature (unless otherwise noted).  $V_{CC}$  = 3.0V to 3.6V  $C_L$  = 50 pF;  $R_L$  = 1.5 k $\Omega$  on D+ to  $V_{CC}$ 

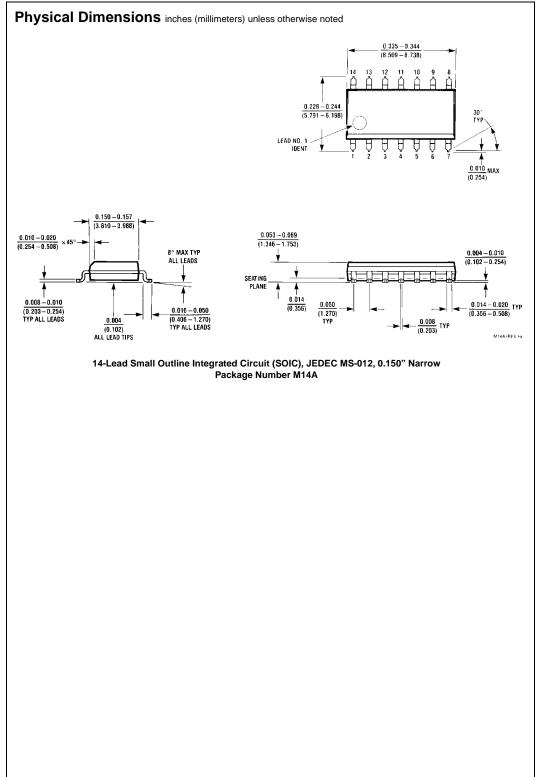
				Limits		
Symbol	Parameter	Test Condition	Tem	p = -40°C to	+85°C	Units
			Min	Тур	Max	
	DRIVER CHARACTERISTICS:		•	•		
		10% and 90%				
t <sub>R</sub>	Rise Time	Figure 1	4		20	ns
t <sub>F</sub>	Fall Time	Figure 1	4		20	
t <sub>RFM</sub>	Rise/Fall Time Matching	$(t_f/t_f)$	90		110	%
V <sub>CRS</sub>	Output Signal Crossover Voltage		1.3		2.0	V
	DRIVER TIMINGS:		•	•		
t <sub>PLH</sub>	Driver Propagation Delay	Figure 2			18	ns
t <sub>PLH</sub>	(VPO, VMO/FSEO to D+/D-)	Figure 2			18	ns
t <sub>PHZ</sub>	Driver Disable Delay	Figure 4			13	ns
t <sub>PLZ</sub>	(OE# to D+/D-)	Figure 4			13	ns
t <sub>PZH</sub>	Driver Enable Delay	Figure 4			17	ns
t <sub>PZL</sub>	(OE# to D+/D-)	Figure 4			17	ns
	RECEIVER TIMINGS:					
t <sub>PLH</sub>	Receiver Propagation Delay	Figure 3			16	ns
t <sub>PHL</sub>	(D+, D- to RCV)	Figure 3			19	ns
t <sub>PLH</sub>	Single-ended Receiver Delay	Figure 3			8	ns
t <sub>PHL</sub>	(D+, D- to VP, VM)	Figure 3			8	ns

# AC Electrical Characteristics (D+/D- Pins, Low Speed)

Over recommended range of supply voltage and operating free air temperature (unless otherwise noted).  $V_{CC} = 3.0 \text{V}$  to 3.6 V C<sub>L</sub> = 200 to 600 pF; R<sub>L</sub> = 1.5k on D- to  $V_{CC}$ 

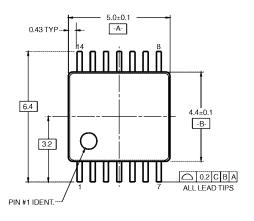
Symbol	Parameter	Test Conditions		Unit		
			T <sub>an</sub>			
			Min	Тур	Max	
	DRIVER CHARACTERISTICS:			I	I	
	_	T	1	T		
		10% and 90%				
$t_{LR}$	Rise Time	Figure 1	75		300	ns
$t_{LF}$	Fall Time	Figure 1	75		300	
t <sub>RFM</sub>	Rise/Fall Time Matching	$(t_r/t_f)$	80		120	%
V <sub>CRS</sub>	Output Signal Crossover Voltage		1.3		2.0	V
	DRIVER TIMINGS:	<u> </u>	•	•		
t <sub>PLH</sub>	Driver Propagation Delay	Figure 2			300	ns
t <sub>PHL</sub>	(VPO, VMO/FSEO to D+/D-)	Figure 2			300	ns
t <sub>PHZ</sub>	Driver Disable Delay	Figure 4			13	ns
t <sub>PLZ</sub>	(OE# to D+/D-)	Figure 4			13	ns
t <sub>PZH</sub>	Driver Enable Delay	Figure 4			205	ns
t <sub>PZL</sub>	(OE# to D+/D-)	Figure 4			205	ns
	RECEIVER TIMINGS:		•	•		•
t <sub>PLH</sub>	Receiver Propagation Delay	Figure 3			18	ns
t <sub>PHL</sub>	(D+, D- to RCV)	Figure 3			18	ns
t <sub>PLH</sub>	Single-ended Receiver Delay	Figure 3			28	ns
t <sub>PHL</sub>	(D+, D- to VP, VM)	Figure 3			28	ns

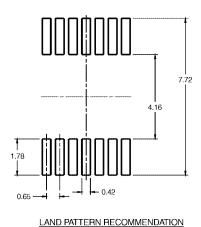




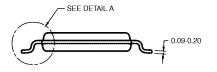
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# Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





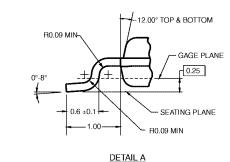
1.2 MAX ALLEAD TIPS 0.90 + 0.15 0.10 0.10 + 0.15 0.10 0.10 + 0.05 0.10 0.10 + 0.13 (M A B S) C S



NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

MTC14RevC3



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

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